

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2	"6249534".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/30 15:59
S2	1172	372/43.01.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/30 15:59
S3	5	S2 and ((semiconductor diode) same laser same active same nitride same algainn)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/30 16:07
S4	41	((semiconductor diode) same laser same active same nitride same algainn)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/30 16:07
S5	8	((semiconductor diode) same laser same active same nitride same algainn) same (gap bandgap)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/30 16:27
S6	11	(semiconductor diode) same laser same active same nitride same (inalgan algainn) same (gap bandgap)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/30 16:16
S7	3	(semiconductor diode) same laser same active same nitride same (inalgan) same (gap bandgap)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:03
S8	1	(semiconductor diode) same laser same active same nitride same ("al. sub.xga.sub.(1-x-y)in.sub.yn") same (gap bandgap)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/30 16:42
S9	0	(semiconductor diode) same laser same active same nitride same ("al. sub.yga.sub.(1-y-x)in.sub.xn") same (gap bandgap)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/30 16:33

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S10	6	(semiconductor diode) same laser same active same nitride same ("al.sub.xga.sub.(1-x-y)in.sub.yn")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:02
S11	2	"20050167836"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/30 18:05
S12	2	"20020150136"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/30 18:05
S13	0	laser same nitride same ("al.sub.xga.sub.(1-x-y)in.sub.yn") same plane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:13
S14	1	laser same nitride same inalgan same plane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:04
S15	61	semiconductor same nitride same inalgan same plane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:05
S16	57	semiconductor same nitride same inalgan same plane same substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:15
S17	1	semiconductor same nitride same ("al.sub.xga.sub.(1-x-y)in.sub.yn") same plane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:13
S18	1	nitride same ("al.sub.xga.sub.(1-x-y)in.sub.yn") same plane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:14
S19	2	nitride same ("al.sub.xga.sub.(1-x-y)in.sub.yn") with thick\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:14

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S20	2	("al.sub.xga.sub.(1-x-y)in.sub.yn") with thick\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:14
S21	23	semiconductor same nitride same inalgan same thick\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/31 14:15